

Pb Free Plating Product

MURF820 thru MURF880



8.0 Ampere Insulated Glass Passivated Ultra Fast Recovery Rectifiers

**Feature**

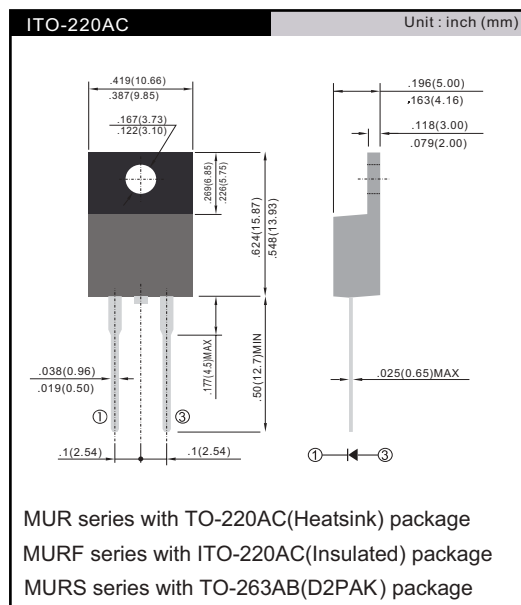
- \* Fast switching for high efficiency
- \* Low forward voltage drop
- \* High current capability
- \* Low reverse leakage current
- \* High surge current capability

**Application**

- \* Switching mode power supply
- \* Inverter/converter
- \* TV receiver, monitor/set top box

**Mechanical Data**

- \* Case: Molded plastic Isolated/Insulated ITO-220AC
- \* Epoxy: UL 94V-0 rate flame retardant
- \* Terminals: Solderable per MIL-STD-202 method 208
- \* Polarity: As marked on diode body
- \* Mounting position: Any
- \* Weight: 2.03 grams approximately



**MAXIMUM RATINGS** ( $T_C = 25\text{ }^\circ\text{C}$  unless otherwise noted)

PARAMETER	SYMBOL	MURF820	MURF840	MURF860	MURF880	UNIT
Maximum recurrent peak reverse voltage	$V_{RRM}$	200	400	600	800	V
Maximum RMS voltage	$V_{RMS}$	140	280	420	560	V
Maximum DC blocking voltage	$V_{DC}$	200	400	600	800	V
Maximum average forward rectified current at $T_C = 100\text{ }^\circ\text{C}$	$I_{F(AV)}$	8.0				A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$	100				A
Maximum slope of reverse recovery current $I_F = 2.0\text{ A}$ , $V_R = 30\text{ V}$ , $di/dt = 20\text{ }\mu\text{s}$	$di/dt$	60				A/ $\mu\text{s}$
Operating junction and storage temperature range	$T_J, T_{STG}$	- 40 to + 150				$^\circ\text{C}$
Isolation voltage (ITO-220AC only) from terminal to heatsink $t = 1\text{ min}$	$V_{AC}$	1500				V

**ELECTRICAL CHARACTERISTICS** ( $T_C = 25\text{ }^\circ\text{C}$  unless otherwise noted)

PARAMETER	TEST CONDITIONS	SYMBOL	MURF820	MURF840	MURF860	MURF880	UNIT
Maximum instantaneous forward voltage <sup>(1)</sup>	8.0 A	$V_F$	0.98	1.3	1.7	1.8	V
Maximum DC reverse current at rated DC blocking voltage	$T_J = 25\text{ }^\circ\text{C}$ $T_J = 125\text{ }^\circ\text{C}$	$I_R$	10 250				$\mu\text{A}$
Maximum reverse recovery time	$I_F = 1.0\text{ A}$ , $V_R = 30\text{ V}$ , $di/dt = 50\text{ A}/\mu\text{s}$ , $I_{rr} = 10\% I_{RM}$	$t_{rr}$	35			50	ns
Maximum recovered stored charge	$I_F = 2.0\text{ A}$ , $V_R = 30\text{ V}$ , $di/dt = 20\text{ A}/\mu\text{s}$	$Q_{rr}$	700				nC

Note: (1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

**THERMAL CHARACTERISTICS** ( $T_C = 25\text{ }^\circ\text{C}$  unless otherwise noted)

PARAMETER	SYMBOL	MURseries	MURF series	MURS series	UNIT
Typical thermal resistance from junction to case	$R_{\theta JC}$	2.0	4.8	2.0	$^\circ\text{C}/\text{W}$
Typical thermal resistance from junction to air	$R_{\theta JA}$	20	-	20	$^\circ\text{C}/\text{W}$

**RATINGS AND CHARACTERISTICS CURVES**

( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted)

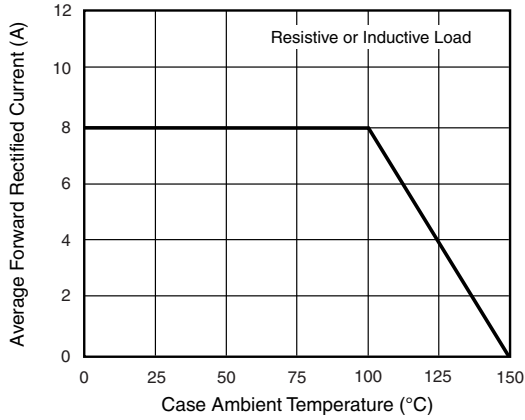


Figure 1. Forward Current Derating Curve

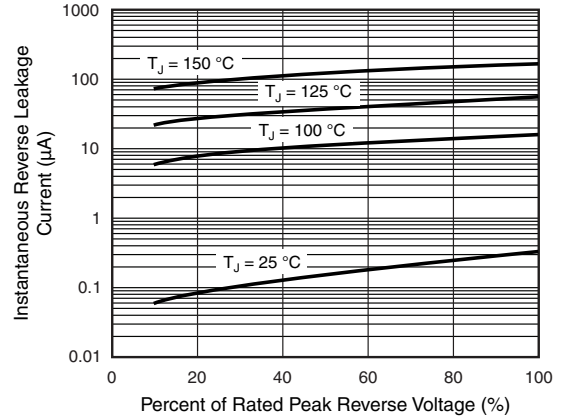


Figure 4. Typical Reverse Leakage Characteristics

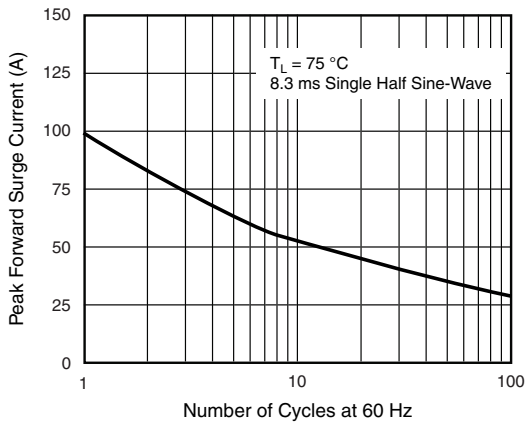


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

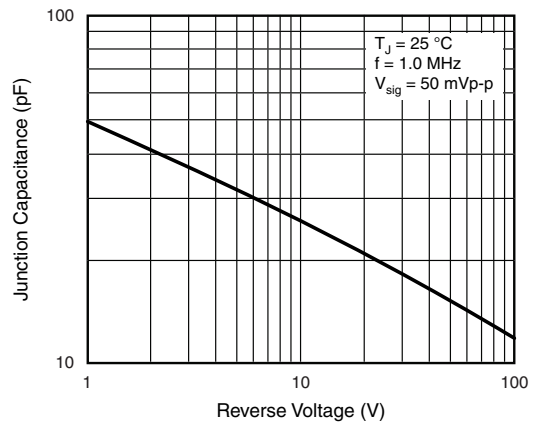


Figure 5. Typical Junction Capacitance

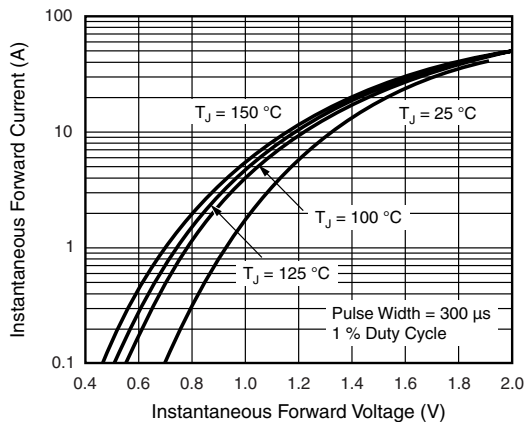


Figure 3. Typical Instantaneous Forward Characteristics